



GBJ35JL

35A SINGLE-PHASE STANDARD RECOVERY BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- High Case Dielectric Strength of 2500V_{RMS}
- Low Forward Voltage Drop
- Low Reverse Leakage Current
- Surge Overload Rating to 400A Peak
- Ideal for Printed Circuit Board Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: GBJ
- Case Material: Molded Plastic. UL Flammability Classification 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Tin Plated Leads(Matte Tin Finish),
 Solderable per MIL-STD-202, Method 208 63
- Polarity: Molded on Body
- Mounting: Through Hole for #6 Screw
- Mounting Torque: 5.0 in-lbs Maximum
- Weight: 6.6 grams (Approximate)



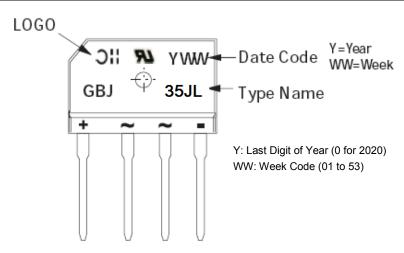
Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
GBJ35JL-F	Commercial	GBJ	15/Tube

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



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Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	600	٧
RMS Reverse Voltage		V _{R(RMS)}	420	V
Average Forward Rectified Output Current (Note 5)	With Heatsink T_C = +80°C Without Heatsink T_C = +25°C	Io	35 4.7	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on rated Load	@ T _J = +25°C @ T _J = +125°C	I _{FSM}	400 320	Α
Non-Repetitive Peak Forward Surge Current 1.0msSingle Half Sine-Wave Superimposed on rated Load	@ T _J = +25°C @ T _J = +125°C	I _{FSM}	800 640	Α
I ² t Rating for Fusing (3ms < t < 8.3ms) (Note 5)		I ² t	664	A ² S
Mounting Torque (Recommended Torque: 0.5N.m)		TOR	0.8	N.m

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Typical Thermal Resistance Junction to Case	(Note 6)	$R_{ heta JC}$	4	°C/W
Typical Thermal Resistance Junction to Lead	(Note 6)	$R_{ heta JL}$	10	°C/W
Typical Thermal Resistance Junction to Ambient	(Note 6)	$R_{ heta JA}$	20	°C/W
Typical Thermal Resistance Junction to Case	(Note 7)	$R_{ heta JC}$	1.0	°C/W
Typical Thermal Resistance Junction to Lead	(Note 7)	$R_{ heta JL}$	2	°C/W
Typical Thermal Resistance Junction to Ambient	(Note 7)	$R_{ heta JA}$	2	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

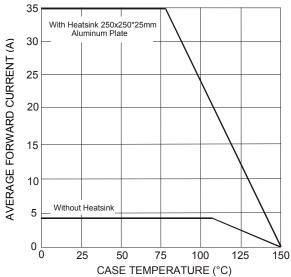
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Breakdown Voltage	V_R	600	_	_	V	$I_R = 10\mu A$
Forward Voltage (Per Element)	V _F	_	0.86	0.92	V	I _F = 17.5A, T _S = +25°C
Reverse Leakage Current (Per Element)	I _R	_	_	10	μA	$V_R = 600V, T_J = +25^{\circ}C$
Total Capacitance (Per Element)	C _T	_	240	_	pF	f = 1MHz, V _R = 4Vdc

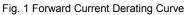
Notes:

- 5. Non-repetitive, for t > 1ms and < 8.3ms.
- 6. Thermal resistance per element without heatsink.
 7. Thermal resistance from junction to case per element. Unit mounted on 250mm x 250mm x 25mm aluminum plate heat sink.

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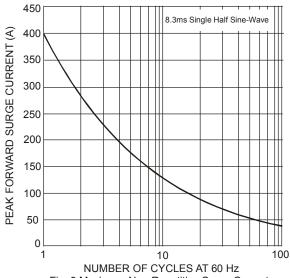


Fig. 3 Maximum Non-Repetitive Surge Current

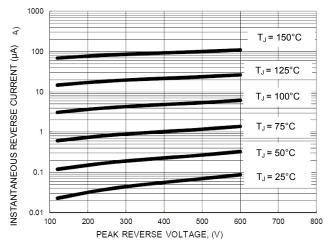


Fig. 5 Typical Reverse Characteristics

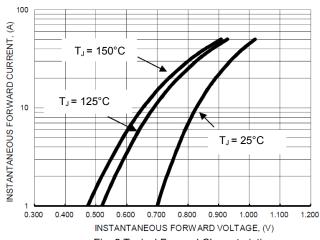


Fig. 2 Typical Forward Characteristics

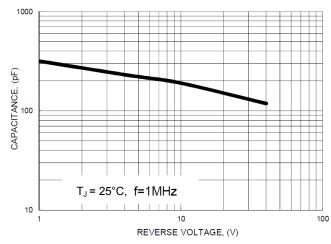


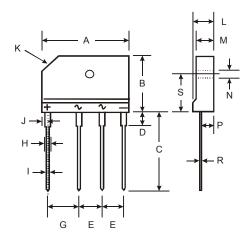
Fig. 4 Typical Junction Capacitance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

GBJ



GBJ					
Dim	Min	Max			
Α	29.70	30.30			
В	19.70	20.30			
С	17.00	18.00			
D	3.80	4.20			
E	7.30	7.70			
G	9.80	10.20			
Н	2.00	2.40			
I	0.90	1.10			
7	2.30	2.70			
K	3.0 X 45°				
L	4.40	4.80			
M	3.40	3.80			
N	3.10	3.40			
Р	2.50	2.90			
R	0.60	0.80			
S	10.80	11.20			
All Dimensions in mm					



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